Single 2-Input Translating AND Gate

GENERAL DESCRIPTION

The 74LV1T08 is a single level translating 2-input AND gate that is designed for 1.6V to 5.5V V_{CC} operation. The input is designed with a low threshold circuit to match 1.8V input logic at V_{CC} = 3.3V and can be used in 1.8V to 3.3V level up translation. In addition, the 5V tolerant input pins enable level down translation (for example, 3.3V to 2.5V output at V_{CC} = 2.5V). The output level is referenced to the supply voltage and supports 1.8V, 2.5V, 3.3V and 5.0V CMOS levels. The wide V_{CC} range allows the generation of output levels to connect to controllers or processors.

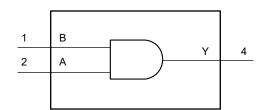
APPLICATIONS

Portable Applications
PC and Notebooks
Automotive
Industrial Controllers
Telecom

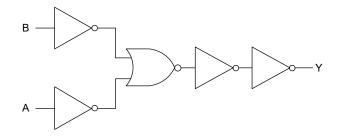
FEATURES

- Single Supply Voltage Translator at 1.8V, 2.5V, 3.3V and 5.0V
- Up Translation:
 - 1.2V to 1.8V at V_{CC} = 1.8V
 - 1.5V to 2.5V at V_{CC} = 2.5V
 - 1.8V to 3.3V at V_{CC} = 3.3V
 - 3.3V to 5.0V at V_{CC} = 5.0V
- Down Translation:
 - 3.3V to 1.8V at V_{CC} = 1.8V
 - 3.3V to 2.5V at V_{CC} = 2.5V
 - 5.0V to 3.3V at V_{CC} = 3.3V
- 5V Tolerant Inputs
- -40°C to +125°C Operating Temperature Range
- Available in a Green SC70-5 Package

LOGIC SYMBOL



LOGIC DIAGRAM



FUNCTION TABLE

INF	INPUT			
Α	В	Υ		
L	L	L		
L	Н	L		
Н	L	L		
Н	Н	Н		

 $Y = A \cdot B$ or $Y = \overline{A} + \overline{B}$

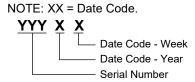
H = High Voltage Level

L = Low Voltage Level

PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
74LV1T08	SC70-5	-40°C to +125°C	74LV1T08XC5G/TR	R59XX	Tape and Reel, 3000

MARKING INFORMATION



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS (1)

ABOULUTE IMAMINUM NATINGO
Supply Voltage, V _{CC} 0.5V to 7V
Input Voltage, V _I ⁽²⁾ 0.5V to 7V
Output Voltage, Vo (2)
Output in High-State or Low-State (3)0.5V to V _{CC} + 0.5V
Output in Power-Off State0.5V to 0.5V
Input Clamping Current, I _{IK} (V _I < 0V)20mA
Output Clamping Current, I_{OK} ($V_O > V_{CC}$ or $V_O < 0V$)
±20mA
Output Current, I_O (V_O = 0V to V_{CC})±25mA
Supply Current, I _{CC} 25mA
Ground Current, I _{GND} 25mA
Junction Temperature ⁽⁴⁾ +150°C
Storage Temperature Range65°C to +150°C
Lead Temperature (Soldering, 10s)+260°C
ESD Susceptibility
HBM4000V
CDM1000V

RECOMMENDED OPERATING	CONDITIONS
Supply Voltage, V _{CC}	
Input Voltage, V _I	0V to 5.5V
Output Voltage, Vo	
Output in High-State or Low-State	0V to V _{CC}
Input Transition Rise and Fall Rate, $\Delta t/\Delta V$	1
V _{CC} = 1.8V to 5.5V	20ns/V (MAX)
Operating Temperature Range	-40°C to +125°C

OVERSTRESS CAUTION

- 1. Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.
- 2. The input and output voltage ratings may be exceeded if the input and output clamp current ratings are observed.
- 3. This value is limited to 7V maximum.
- 4. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

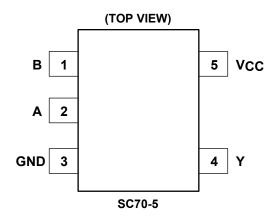
ESD SENSITIVITY CAUTION

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

PIN CONFIGURATION



PIN DESCRIPTION

PIN	NAME	FUNCTION
1, 2	B, A	Data Inputs.
3	GND	Ground.
4	Y	Data Output.
5	Vcc	Supply Voltage.

ELECTRICAL CHARACTERISTICS

(Full = -40°C to +125°C, all typical values are measured at T_A = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL		CONDITIONS		MIN	TYP	MAX	UNITS
		V _{CC} = 1.65V to	1.8V	Full	1			
		V _{CC} = 2.0V		Full	1.03			
		V _{CC} = 2.25V to 2.5V		Full	1.18			
High-Level Input Voltage	V_{IH}	V _{CC} = 2.75V	V _{CC} = 2.75V		1.23			
nigri-Level iriput voltage	VIH	$V_{CC} = 3.0 V \text{ to } 3$	3.3V	Full	1.37]
		V _{CC} = 3.6V		Full	1.48			
		$V_{CC} = 4.5V \text{ to } 5$	5.0V	Full	2.03			
		$V_{CC} = 5.5V$		Full	2.11			
		$V_{CC} = 1.65V \text{ to}$	2.0V	Full			0.55	
Low-Level Input Voltage	V_{IL}	$V_{CC} = 2.25V \text{ to}$	2.75V	Full			0.71	V
Low-Level Input Voltage	VIL	$V_{CC} = 3.0 V \text{ to } 3$	3.6V	Full			0.65	v
		$V_{CC} = 4.5V \text{ to } 5$	5.5V	Full			0.8	
			V_{CC} = 1.65V to 5.5V, I_{O} = -20 μ A	Full	V _{CC} - 0.05	V _{CC} - 0.01		
			$V_{CC} = 1.65V, I_{O} = -2mA$	Full	1.39	1.53		V
		$V_{I} = V_{IH}$ or V_{IL}	$V_{CC} = 1.8V, I_{O} = -2mA$	Full	1.56	1.7		
	V _{он}		$V_{CC} = 2.3V$, $I_{O} = -2.3mA$	Full	2.08	2.22		
			$V_{CC} = 2.3V$, $I_{O} = -3mA$	Full	2.06	2.18		
High-Level Output Voltage			$V_{CC} = 2.5V$, $I_{O} = -3mA$	Full	2.28	2.4		
Tilgh-Level Odiput voltage			$V_{CC} = 3.0V, I_{O} = -3mA$	Full	2.8	2.92		
			$V_{CC} = 3.0V, I_{O} = -5.5mA$	Full	2.7	2.85		
			$V_{CC} = 3.3V$, $I_{O} = -5.5mA$	Full	3.02	3.16		
			$V_{CC} = 4.5V, I_{O} = -4mA$	Full	4.3	4.42		
			$V_{CC} = 4.5V, I_{O} = -8mA$	Full	4.2	4.35		
			$V_{CC} = 5.0V, I_{O} = -8mA$	Full	4.72	4.86		
			V_{CC} = 1.65V to 5.5V, I_{O} = 20 μ A	Full		0.01	0.05	
			$V_{CC} = 1.65V, I_{O} = 2mA$	Full		0.08	0.2	
			$V_{CC} = 2.3V, I_{O} = 2.3mA$	Full		0.06	0.15	
Low-Level Output Voltage	V_{OL}	V _I = V _{IH} or V _{IL}	$V_{CC} = 2.3V, I_{O} = 3mA$	Full		0.08	0.2	V
Low Love Output Voltago	V OL	VI VIH OI VIL	$V_{CC} = 3.0V, I_{O} = 3mA$	Full		0.06	0.15] `
			$V_{CC} = 3.0V, I_{O} = 5.5mA$	Full		0.12	0.24	
			$V_{CC} = 4.5V, I_{O} = 4mA$	Full		0.08	0.2	
			$V_{CC} = 4.5V, I_{O} = 8mA$	Full		0.14	0.35	
Input Leakage Current	l _l	$V_{CC} = 0V \text{ to } 5.5V, V_1 = V_{CC} \text{ or GND}$		Full		±0.01	±1	μA
Supply Current	Icc	$I_O = 0A$	$5V$, 3.3V, 5.0V, $V_I = V_{CC}$ or GND,	Full		0.01	2	μΑ
Additional Supply Comment	٨١	$I_0 = 0\dot{A}$, other	V_{CC} = 1.8V, V_{I} = 0.3V or 1.1V, pins at V_{CC} or GND	Full		0.1	5	μA
Additional Supply Current	ΔI _{CC}	Per input pin, \	$V_{CC} = 5.5V$, $V_{I} = 0.3V$ or 3.4V, pins at V_{CC} or GND	Full		0.4	1	mA

DYNAMIC CHARACTERISTICS

(For test circuit, see Figure 1. Full = -40°C to +125°C, all typical values are measured at T_A = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONI	DITIONS	TEMP	MIN (1)	TYP	MAX (1)	UNITS
			$V_{CC} = 1.8V, C_L = 15pF$	Full	0.5	7.9	15.5	
			V _{CC} = 1.8V, C _L = 30pF	Full	0.5	8.7	18	
			V _{CC} = 2.5V, C _L = 15pF	Full	0.5	5	9.5	
Propagation Delay (2)		A, B to Y,	V _{CC} = 2.5V, C _L = 30pF	Full	0.5	5.3	10	
Propagation Delay	t _{PD}	see Figure 2	V _{CC} = 3.3V, C _L = 15pF	Full	0.1	3.9	7	ns
			V _{CC} = 3.3V, C _L = 30pF	Full	0.1	4	7.8	
			V _{CC} = 5.0V, C _L = 15pF	Full	0.1	2.9	4.5	
			V _{CC} = 5.0V, C _L = 30pF	Full	0.1	3.2	5.2	
Input Capacitance	Cı	$V_1 = V_{CC}$ or GND, $V_{CC} = 3.3V$		+25°C		4		pF
Output Capacitance	Co	$V_{CC} = 0V, V_{O} = GND$		+25°C		9		pF
			V _{CC} = 1.8V	+25°C		6		pF
Power Dissipation Capacitance (3)		Per buffer,	V _{CC} = 2.5V	+25°C		5.5		
	C _{PD}	V_I = GND to V_{CC} , C_L = 30pF, f = 10MHz	V _{CC} = 3.3V	+25°C		5.5		
			V _{CC} = 5.0V	+25°C		6		

NOTES:

- 1. Specified by design and characterization; not production tested.
- 2. t_{PD} is the same as t_{PLH} and t_{PHL} .
- 3. C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times {V_{CC}}^2 \times f_i \times N + \Sigma (C_L \times {V_{CC}}^2 \times f_o)$$

where:

 f_i = Input frequency in MHz.

 f_o = Output frequency in MHz.

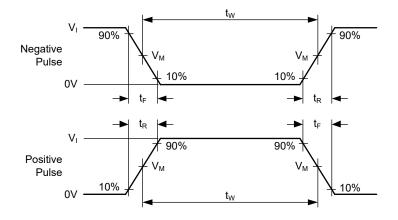
C_L = Output load capacitance in pF.

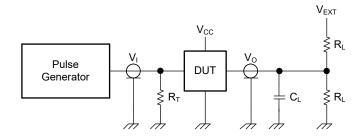
 V_{CC} = Supply voltage in Volts.

N = Number of inputs switching.

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = Sum of the outputs.

TEST CIRCUIT





Test conditions are given in Table 1.

Definitions test circuit:

R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Figure 1. Test Circuit for Measuring Switching Times

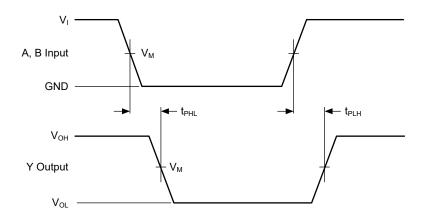
Table 1. Test Conditions

SUPPLY VOLTAGE	INPUT			LO	V _{EXT}	
V _{cc}	Vı	Δt/ΔV ⁽¹⁾	f _{MAX}	C _L	RL	t _{PLH} , t _{PHL}
1.8V	Vcc	≤ 1.0ns/V	15MHz	15pF, 30pF	1ΜΩ	GND
2.5V	Vcc	≤ 1.0ns/V	25MHz	15pF, 30pF	1ΜΩ	GND
3.3V	3V	≤ 1.0ns/V	50MHz	15pF, 30pF	1ΜΩ	GND
5.0V	3V	≤ 1.0ns/V	50MHz	15pF, 30pF	1ΜΩ	GND

NOTE:

1. dV/dt ≥ 1.0V/ns.

WAVEFORMS



Test conditions are given in Table 1.

Measurement points are given in Table 2.

Logic levels: V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Figure 2. The Input A, B to Output Y Propagation Delays

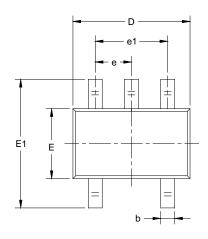
Table 2. Measurement Points

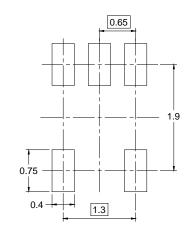
INPUT	OUTPUT		
V _M ⁽¹⁾	V _M		
0.5 × V _I	0.5 × V _{CC}		

NOTE:

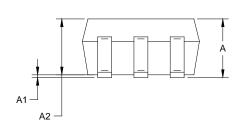
1. The measurement points should be V_{IH} or V_{IL} when the input rising or falling time exceeds 1.0ns.

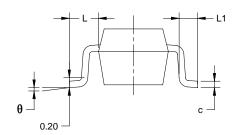
PACKAGE OUTLINE DIMENSIONS SC70-5





RECOMMENDED LAND PATTERN (Unit: mm)

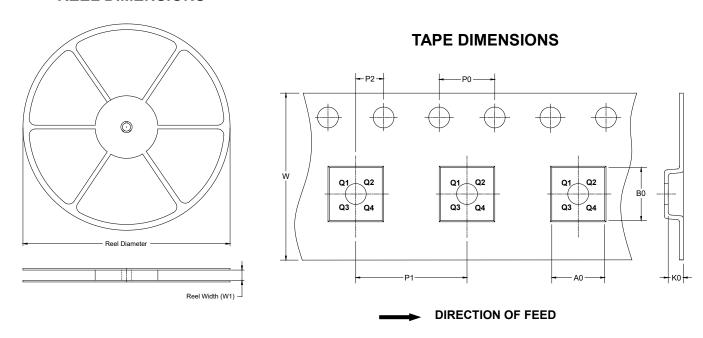




Symbol	_	nsions meters	Dimensions In Inches		
	MIN	MAX	MIN	MAX	
Α	0.800	1.100	0.031	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.800	1.000	0.031	0.039	
b	0.150	0.350	0.006	0.014	
С	0.080	0.220	0.003	0.009	
D	2.000	2.200	0.079	0.087	
E	1.150	1.350	0.045	0.053	
E1	2.150	2.450	0.085	0.096	
е	0.65	TYP	0.026	TYP	
e1	1.300 BSC		0.051 BSC		
L	0.525	REF	0.021	REF	
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

TAPE AND REEL INFORMATION

REEL DIMENSIONS

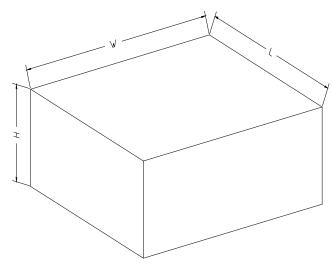


NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SC70-5	7"	9.5	2.25	2.55	1.20	4.0	4.0	2.0	8.0	Q3

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18